

RF AMPLIFIER

MODEL *TM3115*

Available as: TM3115, 4 Pin TO-8 (T4)
 TN3115, 4 Pin .450" sq. Surface Mount (SM3)
 BX3115, SMA Connectorized Housing (H1)

Features

- Low Phase Noise Bipolar Design
- High Output Power: +27 dBm Typical
- Operating Temp. -55 °C to +85 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC		TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		10 - 1400 MHz	10 - 1400 MHz
Gain		13.0 dB	11.5 dB Min.
Power @ 1 dB Comp.	(10-1000 MHz)	27 dBm	25 dBm Min.
	(1000-1200 MHz)	24 dBm	22 dBm Min.
	(1200-1400 MHz)	22 dBm	20 dBm Min.
Reverse Isolation (dB)		-17 dB	-
VSWR	In	1.8:1	2.2:1 Max.
	Out	1.8:1	2.0:1 Max.
Noise Figure (dB)		8.0 dB	10.0 dB Max.
Power	Vdc	+15 volts	+15 volts
	mA	195 mA	210 mA Max.

Typical Intermodulation Performance at 25 °C

Second Order Harmonic Intercept Point +40 dBm (Typ.)
 Second Order Two Tone Intercept Point +35 dBm (Typ.)
 Third Order Two Tone Intercept Point +30 dBm (Typ.)

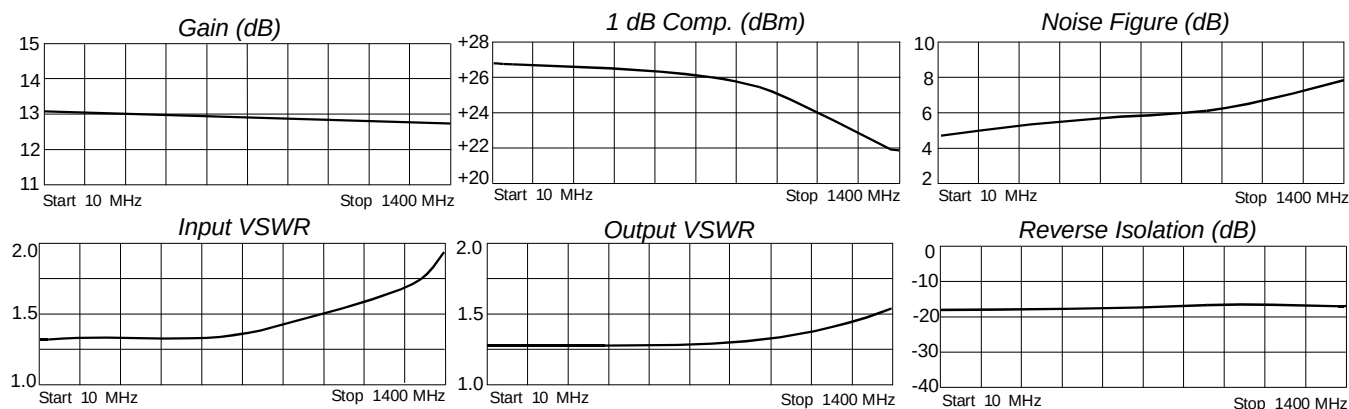
Absolute (No Damage) Maximum Ratings

Ambient Operating Temperature -55°C to +100 °C
 Storage Temperature -62°C to +125 °C
 Case Temperature +125 °C
 DC Voltage +17 Volts
 Continuous RF Input Power +15 dBm
 Short Term RF Input Power 50 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.1 Watt (3 µsec Max.)

(Measured in a 50 Ohm system @ +15 Volts DC nominal unless otherwise noted)

Revision 9-3-2013

Typical Performance Data



Legend ——— +25 °C - - - +85 °C -55 °C

